

TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

2SK370

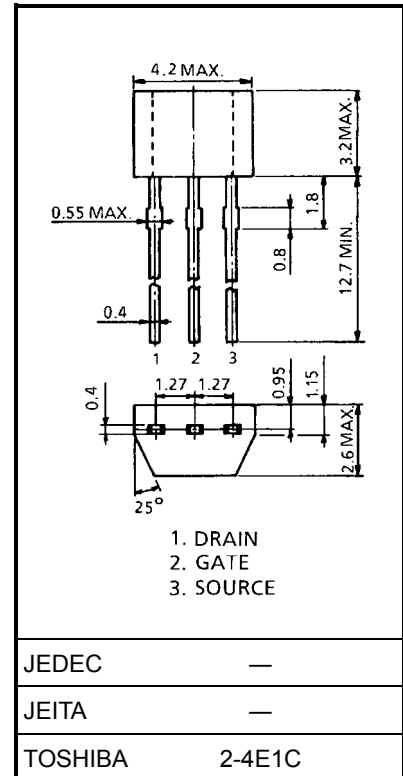
For Low Noise Audio Amplifier Applications

Unit: mm

- Suitable for use as first stage for equalizer and MC head amplifiers.
- High $|Y_{fs}|$: $|Y_{fs}| = 22 \text{ ms (typ.)}$ ($V_{DS} = 10 \text{ V}$, $V_{GS} = 0$, $I_{DSS} = 3 \text{ mA}$)
- High breakdown voltage: $V_{GDS} = -40 \text{ V}$
- High input impedance: $I_{GSS} = -1 \text{ nA (max)}$ ($V_{GS} = -30 \text{ V}$)
- Complementary to 2SJ108
- Small package

Maximum Ratings ($T_a = 25^\circ\text{C}$)

| Characteristics | Symbol | Rating | Unit |
|---------------------------|-----------|---------|------------------|
| Gate-drain voltage | V_{GDS} | -40 | V |
| Gate current | I_G | 10 | mA |
| Drain power dissipation | P_D | 200 | mW |
| Junction temperature | T_j | 125 | $^\circ\text{C}$ |
| Storage temperature range | T_{stg} | -55~125 | $^\circ\text{C}$ |



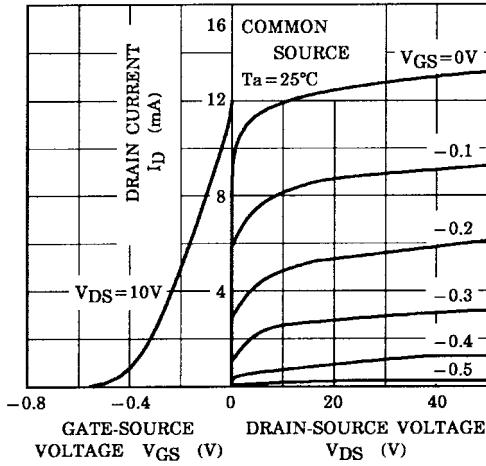
Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Weight: 0.13 g (typ.)

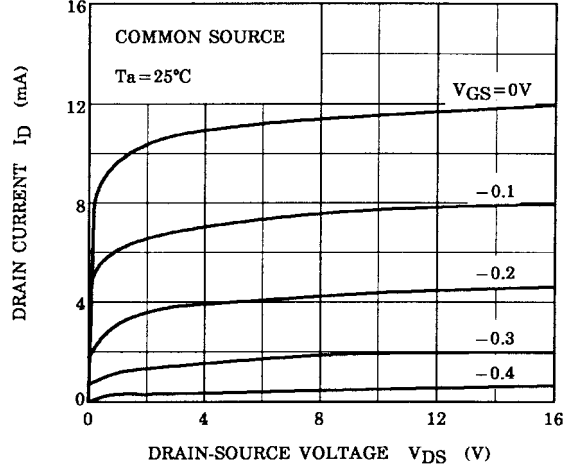
| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|------------------------------|---------------------|---|------|------|------|------|
| Gate cut-off current | I_{GSS} | $V_{GS} = -30 \text{ V}$, $V_{DS} = 0$ | — | — | -1.0 | nA |
| Gate-drain breakdown voltage | $V_{(BR)GDS}$ | $V_{DS} = 0$, $I_G = -100 \mu\text{A}$ | -40 | — | — | V |
| Drain current | I_{DSS} (Note) | $V_{DS} = 10 \text{ V}$, $V_{GS} = 0$ | 2.6 | — | 20 | mA |
| Gate-source cut-off voltage | $V_{GS(OFF)}$ | $V_{DS} = 10 \text{ V}$, $I_D = 0.1 \mu\text{A}$ | -0.2 | — | -1.5 | V |
| Forward transfer admittance | $ Y_{fs} $ | $V_{DS} = 10 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ kHz}$, $I_{DSS} = 3 \text{ mA}$ | 8 | 22 | — | mS |
| Input capacitance | C_{iss} | $V_{DS} = 10 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$ | — | 30 | — | pF |
| Reverse transfer capacitance | C_{rss} | $V_{DG} = 10 \text{ V}$, $I_D = 0$, $f = 1 \text{ MHz}$ | — | 6 | — | pF |
| Noise figure | NF (1) | $V_{DS} = 10 \text{ V}$, $I_D = 1.0 \text{ mA}$, $R_G = 1 \text{ k}\Omega$, $f = 10 \text{ Hz}$ | — | 1.0 | 10 | dB |
| | NF (2) | $V_{DS} = 10 \text{ V}$, $I_D = 1.0 \text{ mA}$, $R_G = 1 \text{ k}\Omega$, $f = 1 \text{ kHz}$ | — | 0.5 | 2 | |

Note: I_{DSS} classification GR: 2.6~6.5 mA, BL: 6.0~12 mA, V: 10~20 mA

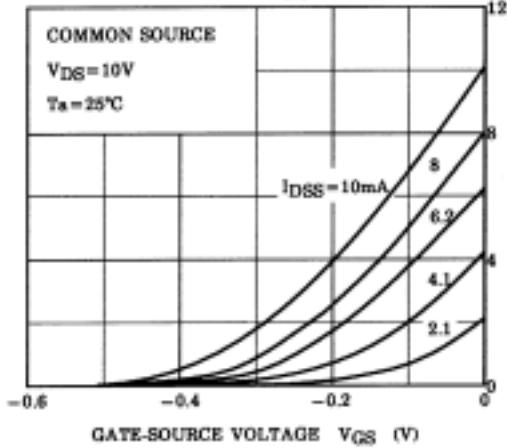
STATIC CHARACTERISTICS



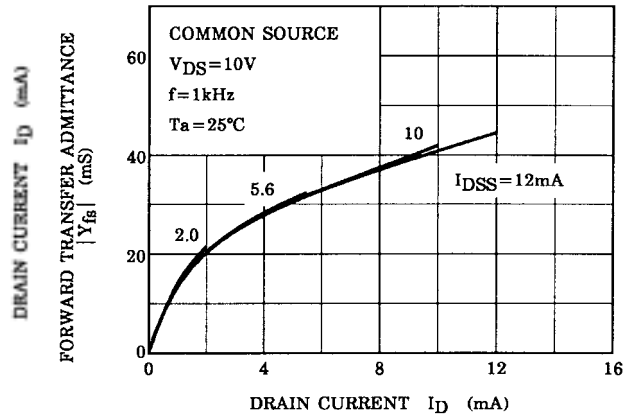
$I_D - V_{DS}$ (LOW VOLTAGE REGION)



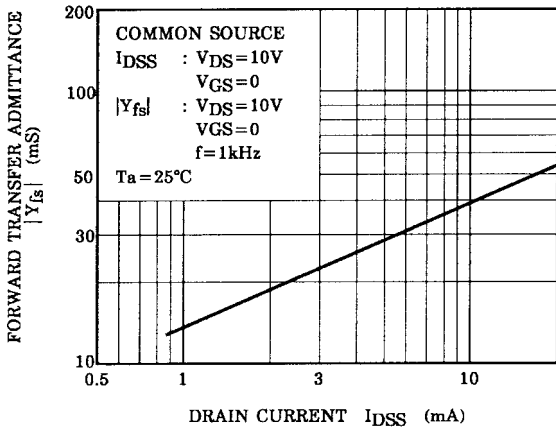
$I_D - V_{GS}$



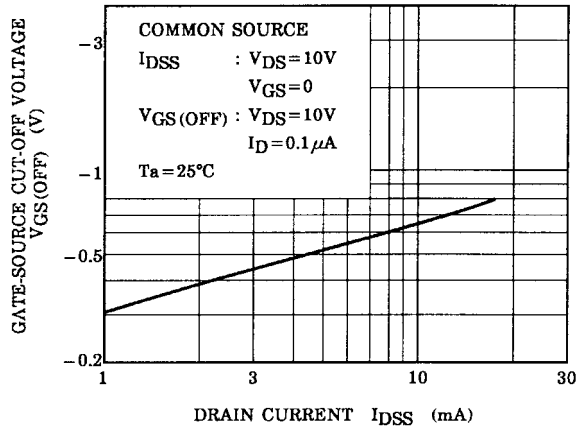
$|Y_{fs}| - I_D$

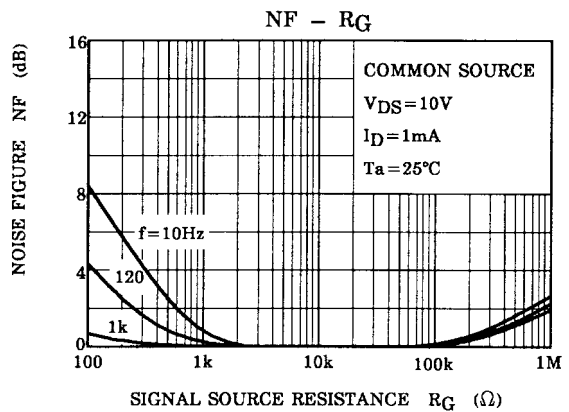
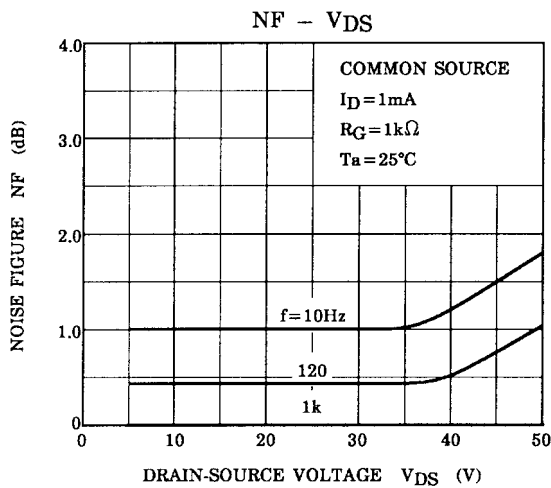
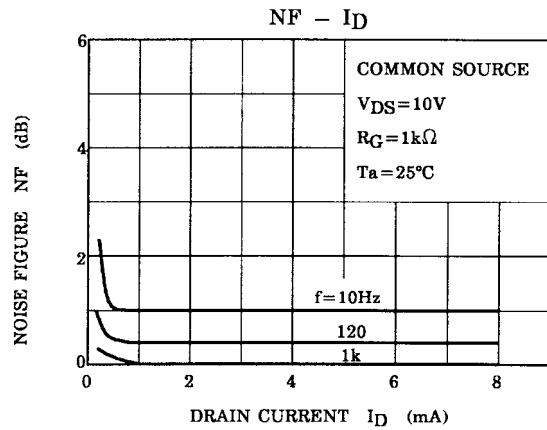
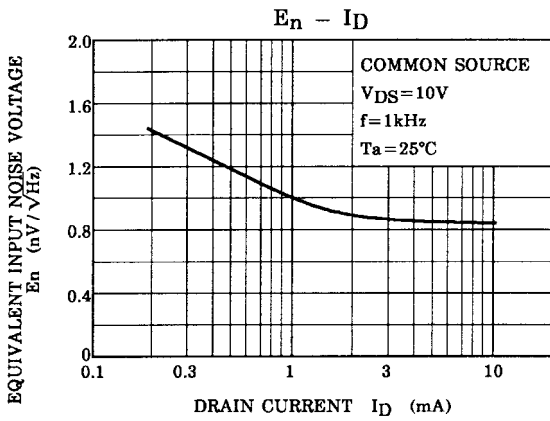
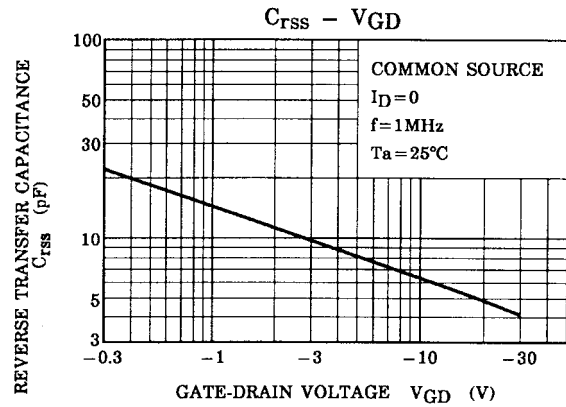
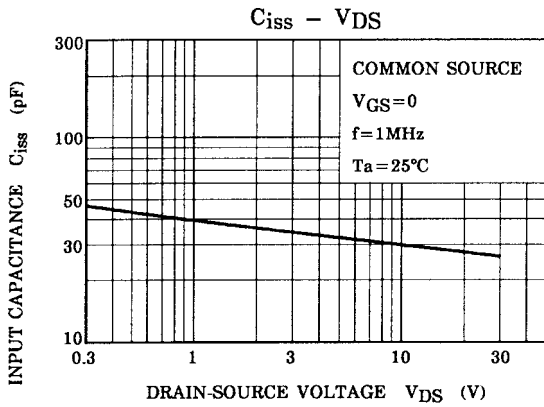


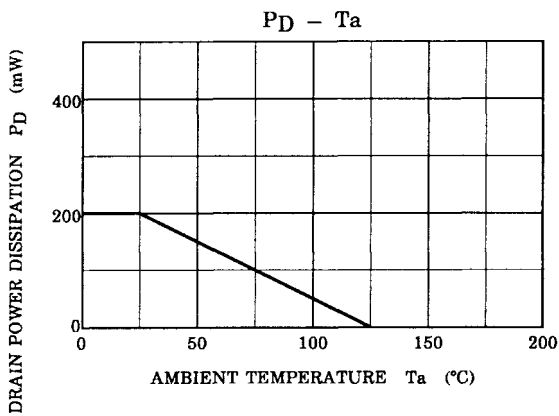
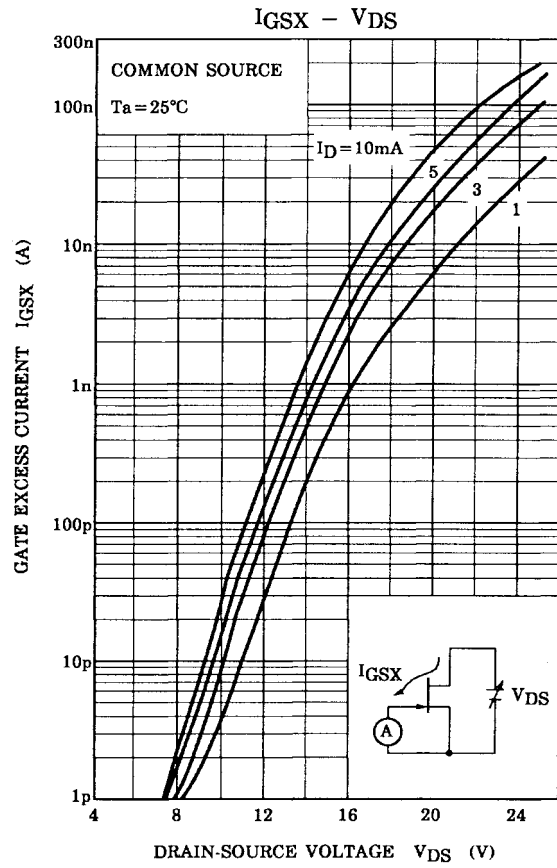
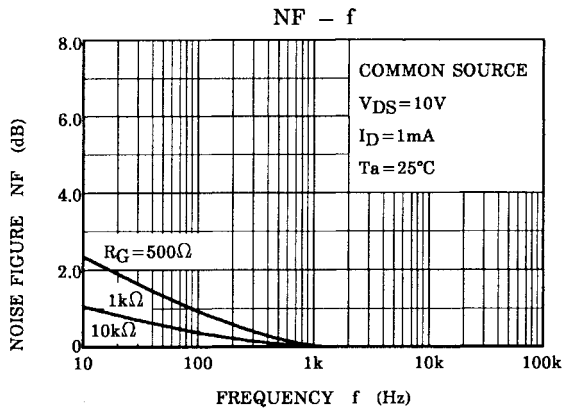
$|Y_{fs}| - I_{DSS}$



VGS(OFF) - IDSS







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